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GAS DISCHARGE TUBES

Gas Discharge Tubes

High Performance Beta Range

RoHS Greentube[™] HV Series Gas Plasma Arresters

The HV Series is a 2-terminal bi-directional, voltage triggered switch designed for the protection of high voltage circuits. Switching voltages for the devices are fixed depending on the part number selected. The gas plasma trigger technology offers very fast switching speeds, high current capability and very low leakage currents.

Features

- · 2 terminal configuration.
- · Very high Isolation up to the specified switching voltage.
- Switching performance is virtually unaffected by changes in ambient temperature.
- UL 1414 class Y2 rated. Listed under file number E56529.
- Moisture resistance as per MIL-STD-202 method 106 (90-98% RH, 65°C).
- Tape and reel to EIA 481-1.

Applications

- · To protect of high voltage circuits.
- To provide isolation between chassis and ground.

this product ways and the product of ↓ Ø 8^{+0.20} Ø**0.8**^{+0.050} 60.0+4 HV XXX A ↓ Ø 8^{+0.20}

60.0 +4 HV XXX C



Mechanical Specifications: Weight: 1.42g (0.049oz.) Materials: Electrode Base: Copper alloy Electrode Plating material: Bright Sn Body: Ceramic **Device Marking:** Littelfuse 'LF marking, voltage and product code



Gas Discharge Tubes

Gas Plasma Voltage Dependent Switches

^{RoHS} Greentube™ HV Series Gas Plasma Arresters

IR

Device Ratings and Specifications

DC Breakover Voltage (V _{BO}) ⁽¹⁾	2850 – 3500 V
Insulation Resistance (Rg) $^{(2)}$	100 MΩ
Max Capacitance (C ₀) ⁽³⁾	1.0 pF
Max Impulse Breakover Voltage (I _{BO}) ⁽⁵⁾	3700 V

Maximum Ratings:

Insulation nesistance (ng) (=/	100 10152				
Max Capacitance (C ₀) ⁽³⁾	1.0 pF				
Max Impulse Breakover Voltage (I _{BO}) ⁽⁵⁾	3700 V]			
Maximum Ratings:					
Impulse Discharge Current ⁽⁴⁾			3 kA, 10 shots		
Storage Temperature T _{STG}			40 - +150°C	.0	
Operating Temperature			40 - +150°C		
Notes:				X	
1) Measured @500 Volts/Second					
2) Measured @1000 Volts DC			1:. 0	Ņ,	
3) Measured @1 MHz, zero Volt bias	;		<u> </u>		
(4) Using 8/20µs double exponential p	oulse	l l	N OI		
5) Measured at 100 Volts/µs rate of ri	se				
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Notes:

- (1) Measured @500 Volts / Second
- (2) Measured @1000 Volts DC
- (3) Measured @1 MHz, zero Volt bias
- (4) Using 8/20µs double exponential pulse
- (5) Measured at 100 Volts/µs rate of rise